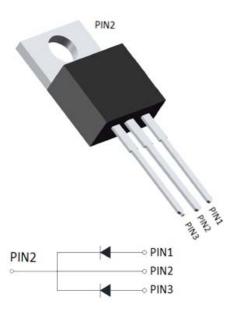


Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: TO-220AB

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

• Polarity: As marked

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRU40100CT
Device marking code			MBRU40100CT
Repetitive Peak Reverse Voltage	V_{RRM}	V	100
Average Rectified Output Current @60Hz sine wave, R-load, Tc=95°C	Io	А	40
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25℃	I _{FSM}	Α	300
Current Squared Time @1ms≤t≤8.3ms Tj=25°C	l ² t	A ² s	373
Storage Temperature	T _{stg}	°C	-55 ~ +150
Junction Temperature	Tj	°C	-55 ~ + 150

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRU40100CT
Maximum instantaneous forward voltage drop per diode	V_{FM}	V	I _{FM} =20.0A	0.71
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	mA	V _{RM} =V _{RRM} Ta=25℃	0.1
	I _{RRM2}		V _{RM} =V _{RRM} Ta=100°C	100

Note1:Pulse test:300uS pulse widh,1% duty cycle

Note2:Pulse test:pulse widh 40mS

Thermal Characteristics $(T_a=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

PARAMETER		SYMBOL	UNIT	MBRU40100CT
Thermal Resistance	Between junction and case	R _{eJ-C}	°CMV	2.0

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRU40100CT	Approximate 1.9	50	1000	5000	Tube

■Characteristics (Typical)

0

0

FIG1:lo -Tc Curve Average Forward Output Current (A) 56.0 48.0 40.0 32.0 TC measure point 24.0 • 16.0 8.0

50

FIG2:Surge Forward Current Capability

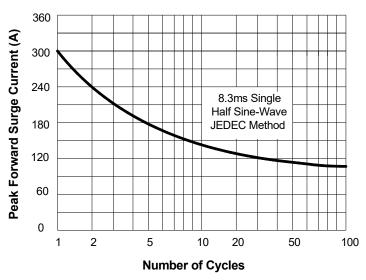


FIG3: Forward Voltage

Case Temperature (°C)

100

150

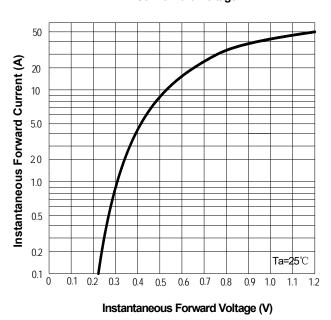
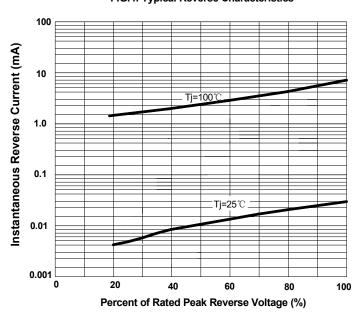
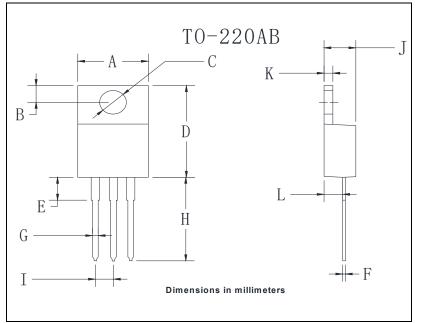


FIG.4: Typical Reverse Characteristics





■Outline Dimensions



TO-220AB				
Dim	Min	Max		
Α	9.95	10.35		
В	2.55	2.95		
С	3.8	4.0		
D	14.95	15.25		
E	3.75	4.25		
F	0.26	0.5		
G	0.68	0.94		
Н	13.4	13.9		
I	2.35	2.65		
J	4.38	4.78		
K	1.14	1.4		
L	2.37	2.79		



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